Diode Semiconductor Device - Page 1 of 1



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Metal	re Material:
	Leveth
	Length:
	n 0.230 inches and 0.300 inches
	al Length:
1.000 in	
	Diameter:
	n 0.104 inches and 0.140 inches
	ectronic Device Engineering Council/jedec/case Outline Designation:
Do-15	
	de Internally-electrically Connected To Case:
Anode	
	ng Method:
Termina	-
	s Provided:
	cally sealed case
Semico	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
50.0 rev	verse voltage, peak
Current	Rating Per Characteristic:
1.00 am	peres source cutoff current preset and 35.00 amperes forward current, average absolute
Maximu	Im Operating Tempurature Per Measurement Point:
150.0 de	egrees celsius junction
Termina	al Type And Quantity:
2 uninsu	lated wire lead
Shelf Li	fe:
N/a	
Unit Of	Measure:
Demilita	arization:
No	
Fiig:	
A110a0	